## **SKMD 202E, SKND 202E**



# SEMIPACK<sup>®</sup> 2

Ultrafast Epitaxial Diode Modules

#### SKND 202E SKMD 202E

#### Features

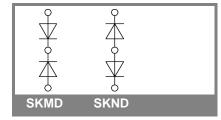
- Isolated metal baseplate
- Very short recovery times
- Low switching losses
- Up to 300 V peak inverse voltage
- SKMD common cathode
  SKND common anode
- UL recognized, file no. E 63 532

### **Typical Applications\***

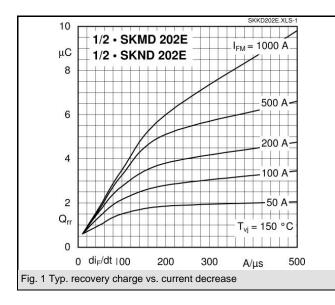
- Switched mode power converters
- Inverse diode for transistors in AC and DC motor controls
- Uninterruptible power supplies
  (UPS)

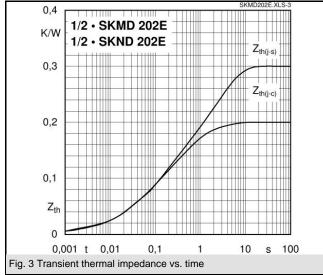
| V <sub>RSM</sub> | V <sub>RRM</sub> | I <sub>FRMS</sub> = 325 A (maximum value for continuous operation) |             |  |
|------------------|------------------|--|-------------|--|
| V                | V                | I <sub>FAV</sub> = 202 A (sin. 180, 50 Hz; T <sub>c</sub> = 87 °C) |             |  |
| 200              | 200              | SKMD 202E02  | SKND 202E02 |  |
| 300              | 300              | SKMD 202E03  | SKND 202E03 |  |

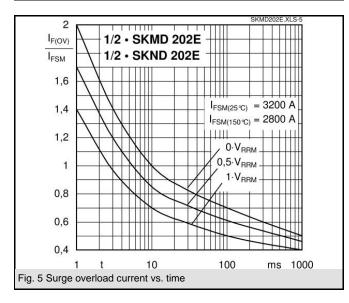
| Symbol               | Conditions   | Values      | Units |
|----------------------|--|-------------|-------|
| I <sub>FAV</sub>     | sin. 180; T <sub>c</sub> = 85 (100) °C                       | 208 (156)   | А     |
| I <sub>FSM</sub>     | T <sub>vi</sub> = 25 °C; 10 ms                               | 3200        | Α     |
|                      | T <sub>vi</sub> = 150 °C; 10 ms                              | 2800        | Α     |
| i²t                  | T <sub>vi</sub> = 25 °C; 8,3 10 ms                           | 51000       | A²s   |
|                      | T <sub>vj</sub> = 150 °C; 8,3 10 ms                          | 39000       | A²s   |
| V <sub>F</sub>       | T <sub>vi</sub> = 25 °C; I <sub>F</sub> = 500 A              | max. 1,65   | V     |
| V <sub>(TO)</sub>    | T <sub>vi</sub> = 150 °C                                     | max. 0,8    | V     |
| r <sub>T</sub>       | T <sub>vj</sub> = 150 °C                                     | max. 1,5    | mΩ    |
| I <sub>RD</sub>      | $T_{vj} = 25 \text{ °C}; V_{RD} = V_{RRM}$                   | max. 2      | mA    |
| I <sub>RD</sub>      | T <sub>vj</sub> = 130 °C; V <sub>RD</sub> = V <sub>RRM</sub> | max. 100    | mA    |
| Q <sub>rr</sub>      | T <sub>vi</sub> = 150 °C, I <sub>F</sub> = 50 A,             | 2           | μC    |
| IRM                  | -di/dt = 100 A/µs, V <sub>R</sub> = 100 V                    | 16          | А     |
| t <sub>rr</sub>      |  | -           | ns    |
| Err                  |  | -           | mJ    |
| R <sub>th(j-c)</sub> | per diode / per module                                       | 0,2 / 0,1   | K/W   |
| R <sub>th(c-s)</sub> | per diode / per module                                       | 0,1 / 0,05  | K/W   |
| T <sub>vj</sub>      |  | - 40 + 150  | °C    |
| T <sub>stg</sub>     |  | - 40 + 125  | °C    |
| V <sub>isol</sub>    | a. c. 50 Hz; r.m.s.; 1 s / 1 min.                            | 3000 / 2500 | V~    |
| M <sub>s</sub>       | to heatsink  | 5 ± 15 %    | Nm    |
| Mt                   | to terminals   | 5 ± 15 %    | Nm    |
| а                    |  | 5 * 9,81    | m/s²  |
| m                    | approx.  | 250         | g     |
| Case                 | SKMD   | A 51        |       |
|                      | SKND   | A 52        |       |
|                      |  |             |       |

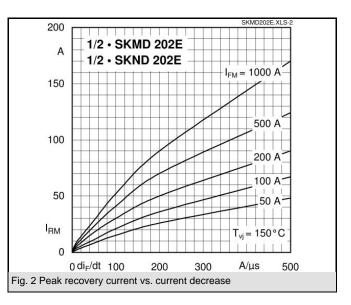


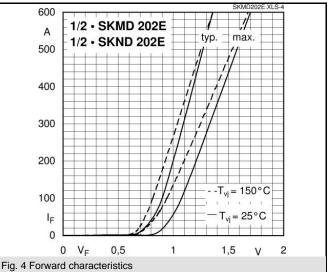
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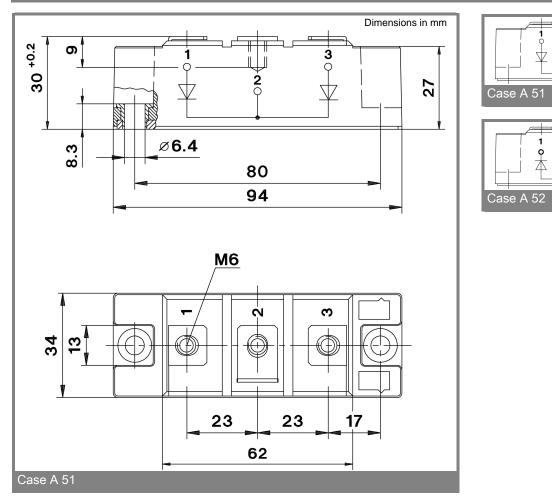








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\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.

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